

Magnetic and transport properties investigation of rare-earth compounds with orthorhombic structures

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The structural, magnetic, magnetoelectric, and ferroelectric properties of a series of monocrystals with perovskite structures have been examined. The investigations were carried out in the temperature range 2–800 K and at magnetic fields up to 14 T. The existence of giant magnetoresistance (GMR) for some samples, a giant magnetostiction effect for others and the presence of multiphase ferroelectric states were demonstrated. Various possibilities for practical applications are discussed.

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1. Introduction

Rare-earth manganites are fascinating, because they display a wide variety of fundamental properties from magnetism to ferroelectricity, from colossal magnetoresistance to semi-metallicity, and because they can be used in a number of important technological applications such as controlling a magnetic memory by an electric field or vice versa, new types of attenuators or transducers etc.

In this paper, we present our investigation on monocrystal samples with an orthorhombic structure, grown in two different space groups: $D_{2h}(16)$ for $\text{La}_{0.78}\text{Pb}_{0.22}\text{MnO}_3$ and $\text{Pr}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ and $D_{2h}(9)$ for HoMn_2O_5 and TbMn_2O_5 .

The doped perovskite manganites $\text{Ln}_{1-x}\text{A}_x\text{MnO}_3$ (where Ln is a rare-earth ion and A is a divalent ion) from the group $D_{2h}(16)$ crystallize in different modifications of the perovskite structure, characterized by a deformation parameter of the type $c/\sqrt{2} < b < a$. Many properties of these compounds (especially the giant magnetoresistance GMR, being interesting for practical applications) depend strongly on the carrier density, the specific zone structure, the type and the quantity of dopants, the defects of the crystal and their magnetic structure, or on the applied magnetic field.

The first two compounds of this investigation: $\text{La}_{0.78}\text{Pb}_{0.22}\text{MnO}_3$ and $\text{Pr}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$, are doped by divalent lead and strontium ions. These ions possess ion radii bigger than that of La, and thus they change the deformation of the perovskite lattice. Also, they cause the appearance of Mn^{4+} and thus introduce ferromagnetic interactions in the lattice (the interaction $\text{Mn}^{3+} - \text{O}^{2-} - \text{Mn}^{4+}$ is positive). Furthermore, they create hole conductivity

and an increase in the mobility of d-electrons [1], thus the carrier density.

The second part of this investigation concerning HoMn_2O_5 and TbMn_2O_5 compounds is aimed at revealing the mediating role of the lanthanide in the appearance of the “giant” magnetostriction effect and electrical polarization.

2. Results and discussion

The magnetic and transport properties (Hall effect, electric resistance) of a $\text{La}_{0.78}\text{Pb}_{0.22}\text{MnO}_3$ sample were measured in a wide temperature range (4.2 – 800 K) and magnetic fields up to 14 T, in order to study the effect of the divalent ion.

The $\text{La}_{0.78}\text{Pb}_{0.22}\text{MnO}_3$ monocrystal is a typical ferromagnetic material, with $T_c = 353$ K. Its electrical resistance as a function of temperature at zero magnetic field is presented in Fig.1, as an insert. The same figure illustrates the dependence $1/\chi = f(T)$, where χ is the susceptibility of the sample (right hand curve). As seen from insert, at $H = 0$ the resistance has a maximal value, where $1/\chi$ tends to zero. The value of the magnetoresistance $\rho(0) - \rho(H)/\rho(H)$ at 300 K is 95 %, and decreases to 45 % at 77 K. The effective magnetic moment of Mn in the paramagnetic region, as determined by our investigation at 4.2K, was $M_{\text{eff}} = 5.1 \mu_B$ (see Fig.1, left hand curve). At 4.2 K, with H parallel or perpendicular to c-axis, the measured values were $4.93 \mu_B$ and $4.73 \mu_B$, respectively.

In Fig. 2 experimental data for the Hall voltage as function of temperature at three different fields are presented. The normal Hall effect coefficient calculated by these data is $R_0 = 1.95 \times 10^{-9} \text{ m}^3/\text{c}$ and the Hall carrier density is $n_H = 3.2 \times 10^{21} \text{ cm}^{-3}$.

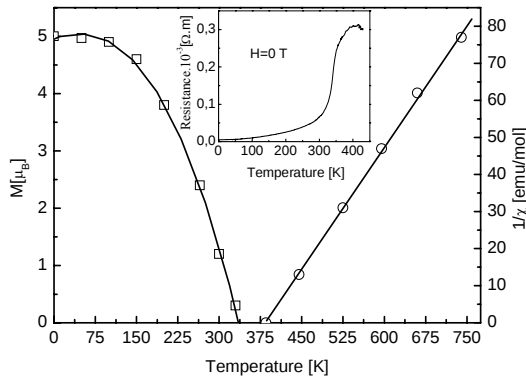


Fig. 1. Resistivity (insert), magnetization and reciprocal susceptibility for $\text{La}_{0.78}\text{Pb}_{0.22}\text{MnO}_3$.

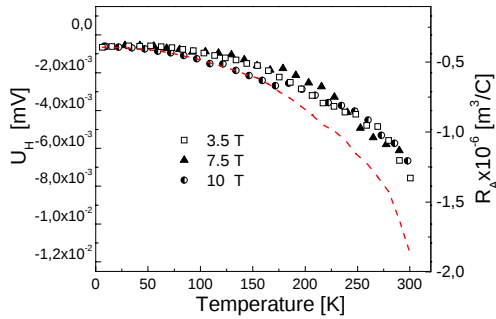


Fig. 2. Temperature dependence of the Hall voltage and anomalous Hall coefficient.

The spontaneous Hall coefficient ($R_a = f(T)$) is presented in the same figure, as a dashed line. The course of the curve is negative, and strongly depends on the temperature due to the additional dissipation of the current carriers by the magnetic moments. This is demonstrated by the sharp decrease in the resistance at temperatures lower than 312 K.

The studies carried out indicate that the $\text{La}_{0.78}\text{Pb}_{0.22}\text{MnO}_3$ compound could be useful for modern microelectronics, since it fulfils two important conditions: it possesses a temperature of magnetic rearrangement (Curie temperature) considerably higher the room temperature and a low electric conductivity, strongly depending on the applied magnetic field.

The investigations on monocrystals of $\text{Pr}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ were inspired by the supposed simultaneous action of different mechanisms of current carrier dissipation and the expected magnetothermal effect in this compound. The results presented in Fig. 3 reveal the temperature dependence of the resistance and magnetic susceptibility. It is shown that the monocrystal is paramagnetic above $T_c = 270$ K and is ferromagnetic at $T < T_c$. At $T = 210$ K, there is another phase transition related to the charge arrangement, and hence to the lattice deformation (see $\chi = f(T)$). This is exactly the region where the sample is strongly conductive (see Fig. 3 $\rho = f(T)$).

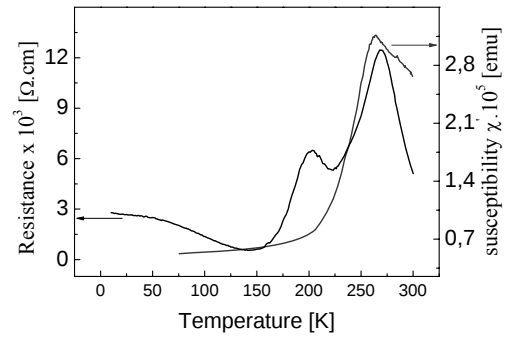


Fig. 3. Electrical resistivity and magnetic susceptibility for $\text{Pr}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ monocrystal.

In Fig. 4, the entropy change ΔS at $H = 1$ T is shown, as a function of temperature. The values for ΔS were obtained after treatment of the data taking into account the magnetic behavior of the monocrystal. It is seen that the effect is maximal near to the transition point $T_c = 270$ K. The obtained maximal value of 2.76 J/kg.K indicates that this composition is suitable for application as a substance for magnetic cooling.

Manganites from the space group $D_{2h}(9)$ attract scientists to study the existing complex magnetoelectric interactions, and provide the opportunity to control them by the application of external magnetic or electric fields [2, 3].

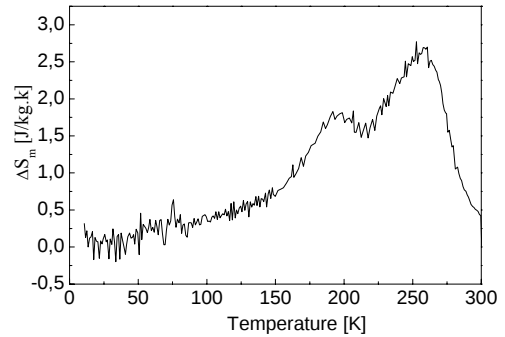


Fig. 4. The temperature dependence of the entropy change ΔS at $H = 1$ T.

Using methods such as XRD, SEM, and EDAX to study the HoMn_2O_5 monocrystal, we have proved that it is orthorhombic with $a = 7.333$ Å, $b = 8.529$ Å and $c = 5.619$ Å. The b-axis of the monocrystal is an axis of easy magnetization and the c axis – of a difficult one. Ho^{3+} , Mn^{3+} and Mn^{4+} occupy respectively the 4g, 4h and 4f locations in the elementary cell.

From the magnetic measurements and the results presented as an insert in Fig. 5, one can determine that the monocrystal is paramagnetic above $T_n = 44$ K with $M_{\text{eff}} = 17.4 \mu_B$ and $\Theta_{\text{paramagnetic}}$ is -130 K. Manganese is ordered antiferromagnetically, with a weak ferromagnetism, and Ho remains paramagnetic down to 5 K polarized by this ferromagnetism [4].

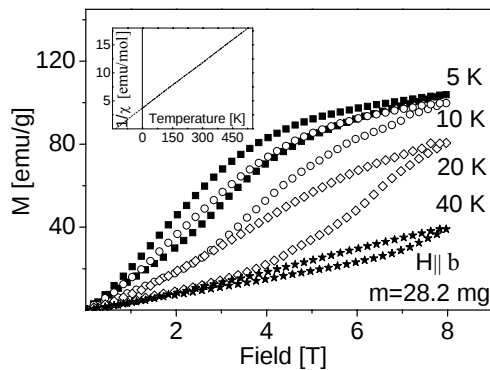


Fig. 5. Reciprocal susceptibility (insert) and magnetization at different temperatures for HoMn_2O_5 .

When a parallel to b-axis field is applied at 5–40 K, significant hysteresis in the magnetization curves is observed, which decreases with decreasing temperature but still remains significant at 4.2 K (Fig. 5).

In Fig. 6, measurements of the dielectric permeability, dielectric losses and the polarization of a HoMn_2O_5 monocrystal, both with and without magnetic fields up to 15 T, are presented. As seen, all parameters measured indicate peculiarities at 40 – 42 K, at 20 – 24 K and at 12 – 15 K.

The changes of the antiferromagnetic structure of HoMn_2O_5 at $H \parallel b$ and T close to 20 – 22 K occur due dominantly to Mn^{4+} , as also indicated by other authors [5, 6]. Near to 12 K, a process of arrangement of Ho^{3+} starts, and is finally completed at lower temperatures.

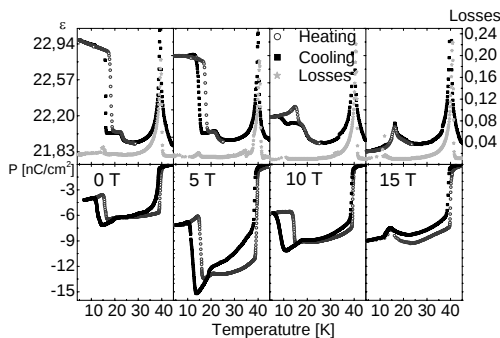


Fig. 6. Dielectric permeability, dielectric losses and polarization of HoMn_2O_5 .

Duplicated material!!

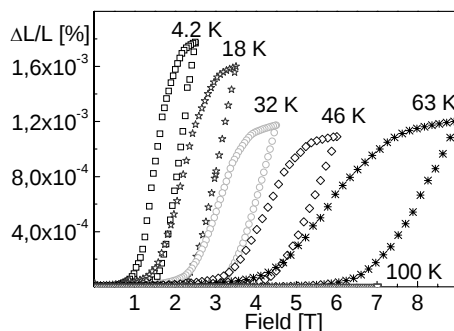


Fig. 7. Magnetostriction of the HoMn_2O_5 monocrystal at different temperatures.

Fig. 7 presents the experimental data from magnetostriction measurements $\lambda = \Delta L/L$ (where L is the sample length and ΔL is its elongation) of a HoMn_2O_5 monocrystal as a function of the field at different temperatures. At 4.2 K and fields above 1.5 T, the “giant” magnetostriction effect is observed, which reaches a value of $2 \cdot 10^{-3}$ for a field of 2 T. For comparison, the same value of λ for pure Ho is reached at three times stronger fields of 6 T at 4.2 K. With increasing temperature, this effect appears at stronger fields, with a decrease in λ . The reason for the observed “giant” magnetostriction is the overlapping of the exchangeable magnetostriction of Mn with the significant mono-ionic magnetostriction of Ho. The drift of Ho in a magnetic field (i.e. its magnetostriction), causes the drift of the rest of the ions, despite the fact that Ho is in a non-ordered state. This process is revealed in a cascade of phase transitions.

The conclusion of the importance of the lanthanide in the appearance of the “giant” magnetostriction was checked by carrying out measurements of the magnetization and magnetostriction of a monocrystal of TbMn_2O_5 in magnetic fields up to 15 T and temperatures down to 4 K.

As seen in Fig. 8, there are some differences both in the types of the $M = f(H)$ curves and in the points of the phase transitions, as compared to the Fig 5 for the HoMn_2O_5 monocrystal. This behavior of the two compounds was also observed by other authors [3, 6, 7]. The terbium manganite also reveals the effect of “giant” magnetostriction (insert in Fig. 8). It should be emphasize that the value of $\lambda = 6.8 \cdot 10^{-3}$ for TbMn_2O_5 is more than 3 times higher than that HoMn_2O_5 . On the other hand, this effect for TbMn_2O_5 appears at 0.5 T (4.2 K) while for the HoMn_2O_5 the effect starts at 1.5 T (4.2 K).

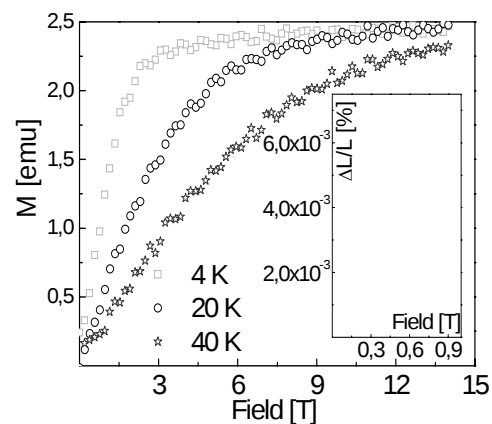


Fig. 8. Magnetization and magnetostriction (insert) as a function of the magnetic field for TbMn_2O_5 .

3. Conclusions

It can be concluded that both the manganites from the space group $D_{2h}(16)$ and those of $D_{2h}(9)$ reveal strong magnetoelectric interactions. Due to these, a number of interesting effects appear, such as “giant” magnetic resistance, a significant magnetothermal effect and “giant”

magnetostriction. The number of the well-known and thoroughly studied pure monocrystals is not very high at present [8]. However, the opportunity for magneto-electric control of their different properties assures its future intensive investigation and possible practical application. A key to the breakthrough is believed to be the use of multiferroics (like HoMn_2O_5 and TbMn_2O_5 , as presented here), where the ferroic orders of (anti)ferromagnetism and (anti)ferroelectricity coexist.

Acknowledgements

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